

Substitute for Form 1449/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
				Application Number	10/593,107
				Filing Date	October 25, 2007
				First Named Inventor:	Shu Yuan
				Art Unit	2892
				Examiner Name	Pham, Hoai V.
Sheet	1	of	5	Attorney Docket Number	7989P003

U.S. PATENT DOCUMENTS						
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* only Abstract in English

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